

MICROPHONE AMPLIFIER

The TAA970 is a monolithic integrated microphone amplifier for use in telephone systems. It is compatible with both piezo-electric and dynamic microphones of suitable impedance and sensitivity.

Special features are:

- almost constant voltage gain and d. c. voltage drop with supply current variations of 10 to 100 mA.
- output voltage before limiting: 1 V (r. m. s. value)
- operation is independent of supply voltage polarity
- gain can be set to either of two values
- only one external capacitor required
- output impedance determined by internal feed back

QUICK REFERENCE DATA

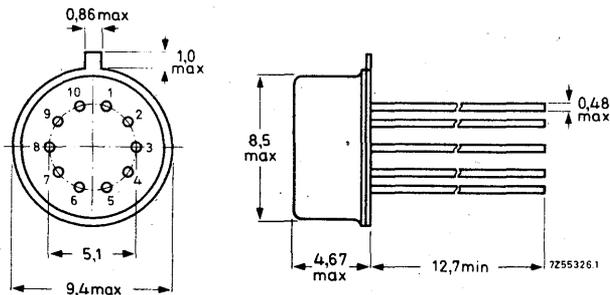
Supply current	$\pm I_2$	10 to 100	mA

Supply voltage drop at $\pm I_2 = 50$ mA	$\pm V_{2-4}$	typ. 4,8	V
Voltage gain			
pin 9 not connected	G_V	typ. 150	
pin 9 connected to pin 10	G_V	typ. 210	
Output impedance			
pin 9 not connected	R_O	typ. 60	Ω
pin 9 connected to pin 10	R_O	typ. 100	Ω

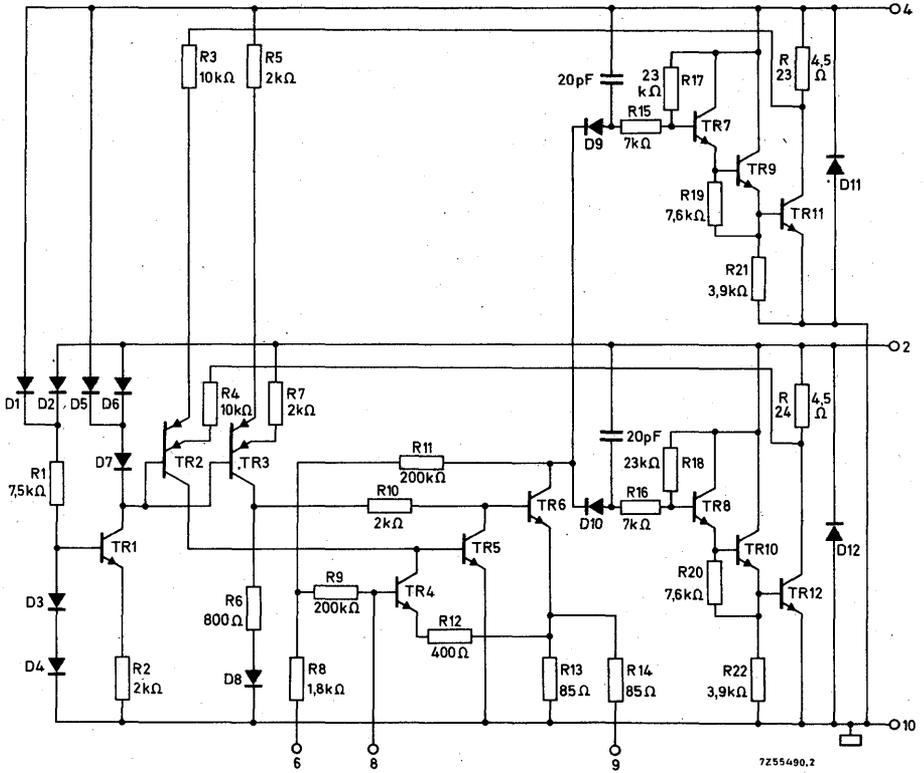
PACKAGE OUTLINE

TO-74 (reduced height)

Dimensions in mm



CIRCUIT DIAGRAM



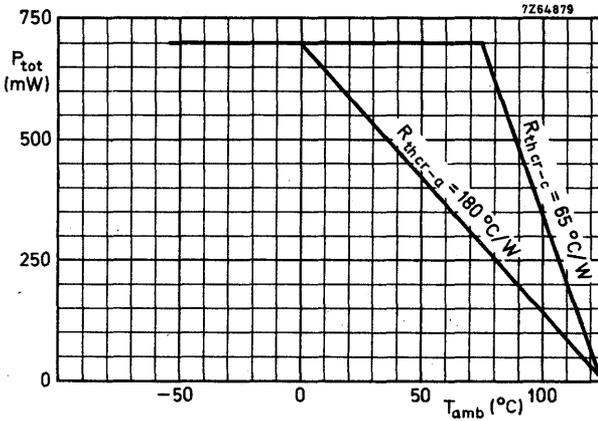
RATINGS Limiting values in accordance with the Absolute Maximum System (IEC 134)

Currents

Supply current (d. c.)	I_2	-100 to +100	mA
A. C. component of supply current (peak value)	I_{2m}	max.	100 mA
Pin No. 6 current	I_6	max.	100 μ A
Pin No. 8 current	I_8	max.	100 μ A

Power dissipation

Total power dissipation	P_{tot}	max.	700 mW
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Temperatures

Storage temperature	T_{stg}	-55 to +125	$^{\circ}$ C
Operating ambient temperature	T_{amb}	-35 to +75	$^{\circ}$ C

THERMAL RESISTANCE

From crystal to case	$R_{th\ cr-c}$	=	65	$^{\circ}$ C/W
From crystal to ambient	$R_{th\ cr-a}$	=	180	$^{\circ}$ C/W

TAA970

CHARACTERISTICS at $R_L = 200 \Omega$; $f = 2 \text{ kHz}$; $T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified.
(see test circuit below).

Supply voltage drop at $R_{th \text{ j-a}} = 100 \text{ }^\circ\text{C/W}$

$\pm I_2 = 10 \text{ mA}$	$\pm V_{2-4}$	3,4 to 5,4 V
$\pm I_2 = 50 \text{ mA}$	$\pm V_{2-4}$	3,8 to 5,8 V
$\pm I_2 = 100 \text{ mA}$	$\pm V_{2-4}$	4,3 to 6,0 V

Voltage gain

pin 9 not connected	$\left\{ \begin{array}{l} \pm I_2 = 10 \text{ mA} \\ \pm I_2 = 50 \text{ mA} \end{array} \right.$	G_V	$\left\{ \begin{array}{l} \text{typ. } 140 \\ 105 \text{ to } 165 \end{array} \right.$
		G_V	$\left\{ \begin{array}{l} \text{typ. } 150 \\ 125 \text{ to } 165 \end{array} \right.$
pin 9 connected to pin 10	$\left\{ \begin{array}{l} \pm I_2 = 10 \text{ mA} \\ \pm I_2 = 50 \text{ mA} \end{array} \right.$	G_V	$\left\{ \begin{array}{l} \text{typ. } 200 \\ 150 \text{ to } 230 \end{array} \right.$
		G_V	$\left\{ \begin{array}{l} \text{typ. } 210 \\ 180 \text{ to } 230 \end{array} \right.$

Change of voltage gain

when changing T_{amb} from $-20 \text{ }^\circ\text{C}$ to $+55 \text{ }^\circ\text{C}$	ΔG_V	< 10 %
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Gain reduction at $f = 300 \text{ Hz}$

(with respect to $f = 2 \text{ kHz}$)	ΔG_V	typ. 1 dB
		< 3 dB

Output impedance at $\pm I_2 = 50 \text{ mA}$

pin 9 not connected	R_O	typ. 60 Ω
pin 9 connected to pin 10	R_O	typ. 100 Ω

Noise output voltage at $B = 0,3 \text{ kHz to } 4 \text{ kHz}$

pin 9 not connected	$V_{n(\text{rms})}$	< 1 mV
pin 9 connected to pin 10	$V_{n(\text{rms})}$	< 1,3 mV

Output voltage

$I_2 = 25 \text{ mA}$; $d_{tot} = 5\%$	V_O	> 0,85 V
		typ. 1,0 V

Test circuit:

